

BYV26A, BYV26B, BYV26C, BYV26D, BYV26E

Vishay Semiconductors

Ultra-Fast Avalanche Sinterglass Diode



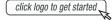
FEATURES

- · Glass passivated junction
- · Hermetically sealed package
- · Very low switching losses
- Low reverse current
- High reverse voltage
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



ROHS COMPLIANT HALOGEN FREE

DESIGN SUPPORT TOOLS





MECHANICAL DATA

Case: SOD-57

Terminals: plated axial leads, solderable per MIL-STD-750,

method 2026

Polarity: color band denotes cathode end

Mounting position: any Weight: approx. 369 mg

APPLICATIONS

- Switched mode power supplies
- High-frequency inverter circuits

| ORDERING INFORMATION (Example) | | | | | | |
|---------------------------------------------------------|------------|----------------------------|--------|--|--|--|
| DEVICE NAME ORDERING CODE TAPED UNITS MINIMUM ORDER QUA | | | | | | |
| BYV26E | BYV26E-TR | 5000 per 10" tape and reel | 25 000 | | | |
| BYV26E | BYV26E-TAP | 5000 per ammopack | 25 000 | | | |

| PARTS TABLE | | | | | |
|-------------|---------------------------------------------------|---------|--|--|--|
| PART | TYPE DIFFERENTIATION | PACKAGE | | | |
| BYV26A | V _R = 200 V; I _{F(AV)} = 1 A | SOD-57 | | | |
| BYV26B | V _R = 400 V; I _{F(AV)} = 1 A | SOD-57 | | | |
| BYV26C | $V_R = 600 \text{ V}; I_{F(AV)} = 1 \text{ A}$ | SOD-57 | | | |
| BYV26D | $V_R = 800 \text{ V}; I_{F(AV)} = 1 \text{ A}$ | SOD-57 | | | |
| BYV26E | V _R = 1000 V; I _{F(AV)} = 1 A | SOD-57 | | | |

| ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified) | | | | | | |
|---------------------------------------------------------------------------------|----------------------------------------|--------|--------------------|-------------|------|--|
| PARAMETER | TEST CONDITION | PART | SYMBOL | VALUE | UNIT | |
| | See electrical characteristics | BYV26A | $V_R = V_{RRM}$ | 200 | V | |
| | | BYV26B | $V_R = V_{RRM}$ | 400 | V | |
| Reverse voltage = repetitive peak reverse voltage | | BYV26C | $V_R = V_{RRM}$ | 600 | V | |
| Vollage | | BYV26D | $V_R = V_{RRM}$ | 800 | V | |
| | | BYV26E | $V_R = V_{RRM}$ | 1000 | V | |
| Peak forward surge current | $t_p = 10 \text{ ms}$, half sine wave | | I _{FSM} | 30 | Α | |
| Average forward current | | | I _{F(AV)} | 1 | Α | |
| Non repetitive reverse avalanche energy | $I_{(BR)R} = 1 A$, inductive load | | E _R | 10 | mJ | |
| Junction and storage temperature range | | | $T_j = T_{stg}$ | -55 to +175 | °C | |

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| MAXIMUM THERMAL RESISTANCE (T _{amb} = 25 °C, unless otherwise specified) | | | | | | |
|-----------------------------------------------------------------------------------|--------------------------------------|-------------------|-------|------|--|--|
| PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT | | |
| Junction ambient | I = 10 mm, T _L = constant | R _{thJA} | 45 | K/W | | |

| PARAMETER | TEST CONDITION | PART | SYMBOL | MIN. | TYP. | MAX. | UNIT |
|---------------------------|-----------------------------------------------------------------------|--------|--------------------|------|------|------|------|
| Forward voltage | I _F = 1 A | | V_{F} | - | - | 2.5 | V |
| | I _F = 1 A, T _j = 175 °C | | V_{F} | - | - | 1.3 | V |
| Reverse current | $V_R = V_{RRM}$ | | I _R | - | - | 5 | μA |
| | $V_R = V_{RRM}$, $T_j = 150$ °C | | I_R | - | - | 100 | μA |
| Reverse breakdown voltage | I _R = 100 μA | BYV26A | V _{(BR)R} | 300 | - | - | V |
| | | BYV26B | V _{(BR)R} | 500 | - | - | V |
| | | BYV26C | V _{(BR)R} | 700 | - | - | V |
| | | BYV26D | V _{(BR)R} | 900 | - | - | V |
| | | BYV26E | V _{(BR)R} | 1100 | - | - | V |
| Reverse recovery time | I _F = 0.5 A, I _R = 1 A, i _R = 0.25 A | BYV26A | t _{rr} | - | - | 30 | ns |
| | | BYV26B | t _{rr} | - | - | 30 | ns |
| | | BYV26C | t _{rr} | - | - | 30 | ns |
| | | BYV26D | t _{rr} | - | - | 75 | ns |
| | | BYV26E | t _{rr} | - | - | 75 | ns |

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

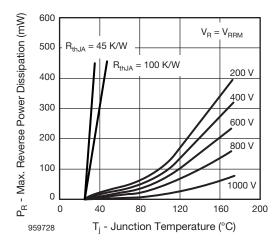


Fig. 1 - Max. Reverse Power Dissipation vs. Junction Temperature

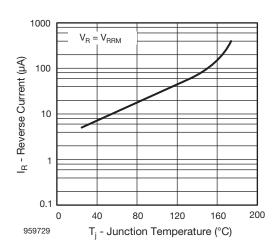


Fig. 2 - Max. Reverse Current vs. Junction Temperature

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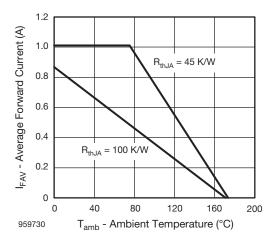


Fig. 3 - Max. Average Forward Current vs. Ambient Temperature

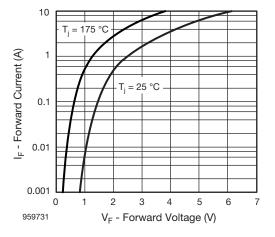


Fig. 4 - Max. Reverse Current vs. Junction Temperature

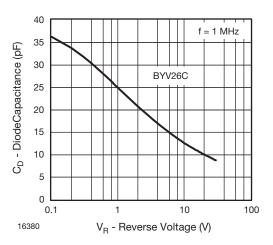


Fig. 5 - Diode Capacitance vs. Reverse Voltage

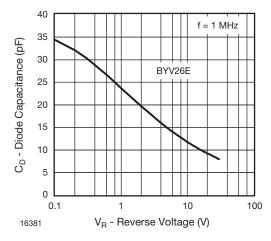
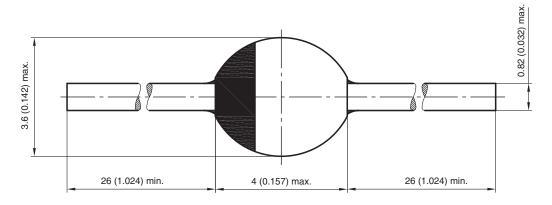


Fig. 6 - Diode Capacitance vs. Reverse Voltage

PACKAGE DIMENSIONS in millimeters (inches): SOD-57



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